

Block Diagram

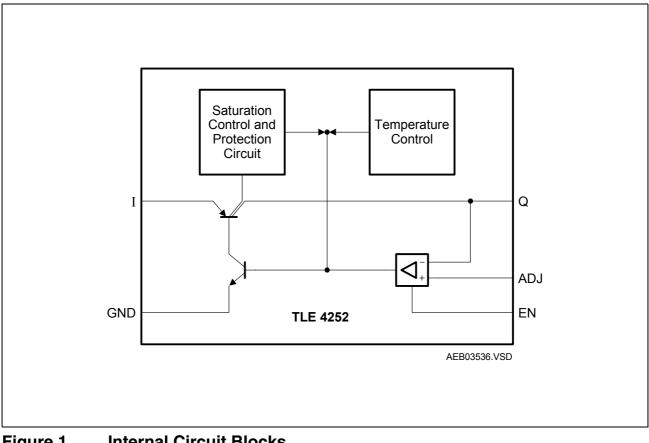


Figure 1 **Internal Circuit Blocks**



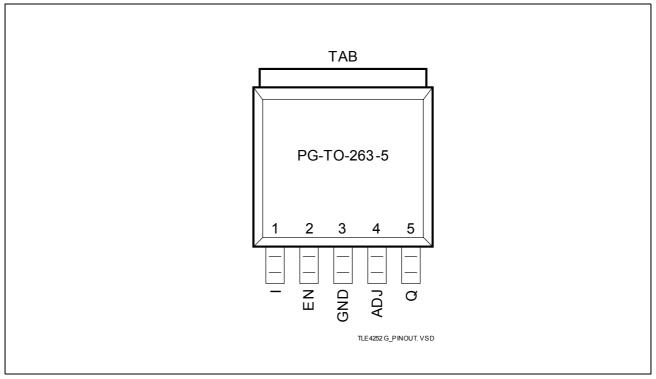


Figure 2 Pin Configuration

Table 1Pin Definitions and Functions

Pin No.	Symbol	Function
1	I	Supply Voltage Input; Input for battery or a pre-regulated voltage of a e.g. a DC to DC converter. For compensating line influences, a capacitor to GND close to the IC pins is recommended.
2	EN	Enable Input; a high signal turns on the IC, with a low signal the tracking regulator is turned off.
3	GND	Ground; connect to TAB.
4	ADJ	Adjust Input; input for the reference voltage which can be connected directly or by voltage divider to the reference (see "Application Information" on Page 8).
5	Q	Regulator Output; block to GND with a capacitor close to the IC pins, respecting the values given for its capacitance C_Q and ESR in table "Functional Range" on Page 5.
TAB	-	Connect to GND and heatsink area.

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Parameter	Symbol	Limi	it Values	Unit	Remarks	
		Min.	Max.			
Supply Voltage Input	1	L				
Voltage	V_1	-42 45		V	-	
Current	I			Α	Limited internally ¹⁾	
Enable Input EN		L				
Voltage	V_{EN}	-42	45	V	-	
Current I _{EN}		_	-	Α	Limited internally	
Adjust Input ADJ		L				
Voltage	V_{ADJ}	-42	2 45 V		-	
Current	I _{ADJ}	– –		Α	Limited internally	
Output Q					•	
Voltage	VQ	⁷ _Q -2 45		V	-	
Current I _Q		_	_	Α	Limited internally	
Temperature					•	
Junction temperature	T _j	-40	150	°C	-	
Storage temperature	T _{stg}	-50	150	°C	-	
ESD-Protection	·		·			
Voltage V _{ESD}		-2	2	kV	Human Body Model (HBM)	

Table 2Absolute Maximum Ratings

 For reverse current flowing in case of negative supply voltage, see table "Electrical Characteristics" on Page 6. A reverse current may heat up the device. The integrated temperature protection is not operating at negative supply voltage.

- Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation



Table 3Functional Range

Parameter	Symbol	Limit Values			Unit	Remarks
		Min.	Тур.	Max.		
In- and Output Voltag	ge					
Supply voltage	VI	3.5	_	40	V	$V_{\rm I} > V_{\rm ADJ} + V_{\rm dr}$
Enable input voltage	V_{EN}	0	_	40	V	-
Adjust input voltage	V_{ADJ}	1.5	_	40	V	-
Error amplifier common mode range	CMR	1.5	-	V ₁ - 0.5	V	$V_{\rm Q} \leq V_{\rm ADJ} + \Delta V_{\rm Q}$ with $V_{\rm FB} = V_{\rm Q}$
Output Capacitor						
Output Capacitor's	CQ	10	_	_	μF	-
Requirement	$ESR(C_Q)$	-	-	5	Ω	1)
Temperature		•	•	•	•	
Junction temperature	T _j	-40	_	150	°C	-
1) Belevant ESB value at f	= 10 kHz Nc	t subject	to produc	tion test. s	pecified	by design

1) Relevant ESR value at f = 10 kHz. Not subject to production test; specified by design.

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

Table 4Thermal Resistance PG-TO263-5 1)

Parameter	Symbol	Limit Values			Unit	Remarks
		Min.	Тур.	Max.		
Junction to case	$R_{ m thJC}$	_	4.7	6	K/W	-
Junction to ambient	$R_{ m thJA}$	-	24	-	K/W	2s2p PCB ²⁾
		-	35	-	K/W	PCB heat sink area 600 mm ^{2 3)}
		_	44	-	K/W	PCB heat sink area 300 mm ^{2 3)}

1) Not subject to production test; specified by design.

2) Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable, a thermal via array under the tab contacted the first inner copper layer.

 Specified R_{thJA} value is according to Jedec JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm3 board with 1 copper layer (1 x 70 μm Cu).



Table 5 Electrical Characteristics

 $V_{\rm I}$ = 13.5 V; 1.5 V $\leq V_{\rm ADJ} \leq V_{\rm I}$ - 0.6 V; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition				
		Min.	Тур.	Max.						
Regulator Performance, Tracker Output Q										
Output voltage tracking accuracy $\Delta V_{\rm Q} = V_{\rm ADJ} - V_{\rm Q}$	ΔV_{Q}	-10	-	10	mV	4.5 V < V _I < 26 V; 1 mA < I _Q < 200 mA;				
Output voltage tracking accuracy	ΔV_{Q}	-10	-	10	mV	$3.5 \text{ V} < V_1 < 32 \text{ V};$ 10 mA < I_Q < 100 mA;				
$\Delta V_{\rm Q} = V_{\rm ADJ} - V_{\rm Q}$		-25	-	25	mV	3.5 V < V _I < 4.5 V; 1 mA < I _Q < 200 mA;				
Dropout voltage	V _{dr}	_	280	600	mV	$I_{\rm Q}$ = 200 mA; $V_{\rm ADJ}$ > 3.5 V; $V_{\rm EN}$ = $V_{\rm EN, on}^{1}$				
Output current limitation	$I_{\rm Q,lim}$	250	350	500	mA	$V_{\rm Q} = 5.0 \ {\rm V}^{\ 2)}$				
Output capacitor	C _Q	10	-	—	μF	$0 \le ESR \le 5 \Omega$ at 10 kHz				
Current consumption $I_q = I_l - I_Q$	I _q	_	10	25	mA	$I_{\rm Q}$ = 200 mA; $V_{\rm Q}$ = 5 V				
Current consumption $I_{q} = I_{I} - I_{Q}$	Iq	_	100	150	μA	$I_{\rm Q}$ < 100 µA; $T_{\rm j}$ < 85 °C; $V_{\rm EN}$ = 5 V				
Quiescent current (stand-by) $I_{q} = I_{l} - I_{Q}$	Iq	-	0	2	μA	$V_{\text{EN}} = 0 \text{ V};$ $V_{\text{EN/ADJ}} = 0 \text{ V};$ $T_{\text{j}} < 85 \text{ °C}$				
Reverse current	I _r	-	0.5	5	mA	$V_{\rm Q} = 16 \text{ V}; V_{\rm I} = 0 \text{ V}$				
Load regulation	ΔV_{Q}	-	_	10	mV	1 mA < I _Q < 200 mA				
Line regulation	ΔV_{Q}	_	-	10	mV	$5 V < V_1 < 32 V;$ $I_Q = 5 mA$				
Power supply ripple rejection	PSSR	_	60	-	dB	$f_{\rm I, \ ripple} = 100 \ {\rm Hz};$ $V_{\rm I, \ ripple} = 0.5 \ {\rm Vpp}^{3)}$				



Table 5Electrical Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V; 1.5 V $\leq V_{\rm ADJ} \leq V_{\rm I}$ - 0.6 V; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter	Symbol	mit Val	nit Values		Test Condition		
		Min.	Тур.	Max.			
Adjust Input ADJ						-	
Input biasing current	I _{ADJ}	_	0.1	0.5	μA	$V_{\rm ADJ} = 5 \text{ V}$	
Enable Input EN							
Device on voltage range	$V_{\rm EN, \ on}$	2.0	_	40	V	$V_{\rm Q}$ settled	
Device off voltage range	$V_{\rm EN, \ off}$	0	-	0.8	V	V _Q < 0.1 V	
Input current	I _{EN}	-1	2	5	μA	$V_{\rm EN} = 5 \ { m V}$	
EN pull-down resistor	R _{EN}	-	1.5	_	MΩ	_	

1) Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value.

2) The current limit depends also on the input voltage, see graph output current vs. input voltage in the diagrams section.

3) Specified by design. Not subject to production test.

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Application Information

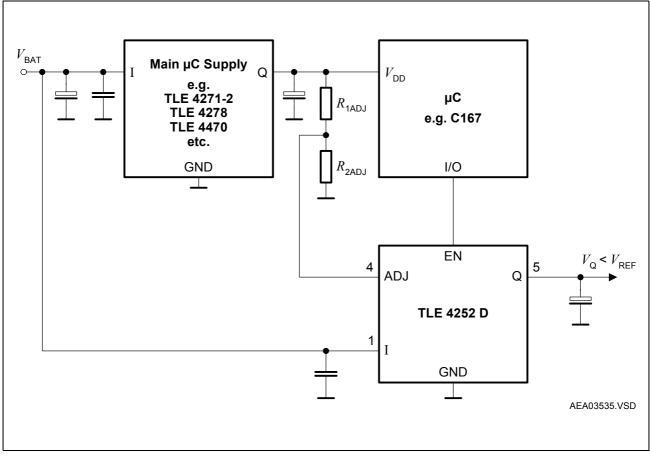


Figure 3 Application Circuit: Output Voltage < Reference Voltage

Figure 3 shows a typical application circuit with $V_Q < V_{REF}$. Of course, also $V_Q = V_{REF}$ is feasible by directly connecting the reference pin of the TLE 4252 D to the appropriate voltage level without voltage divider.

The output voltage calculates to:

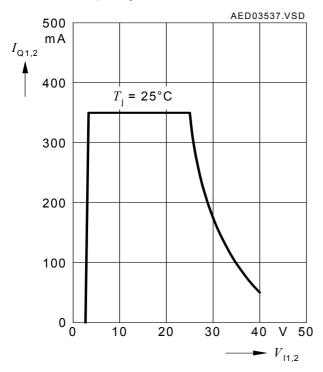
$$V_{\rm Q} = V_{\rm REF} \times \left(\frac{R_{\rm 2ADJ}}{R_{\rm 1ADJ} + R_{\rm 2ADJ}}\right)$$
(1)

Data Sheet

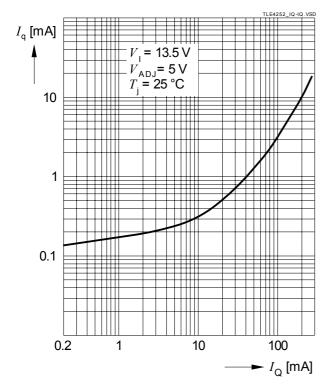


Typical Performance Characteristics

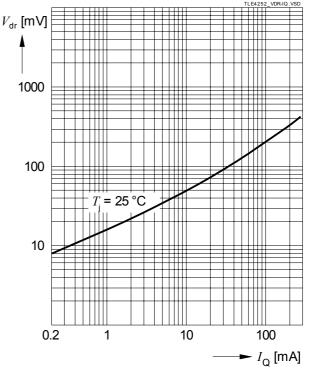
Output Current Limit I_Q versus Input Voltage V_I



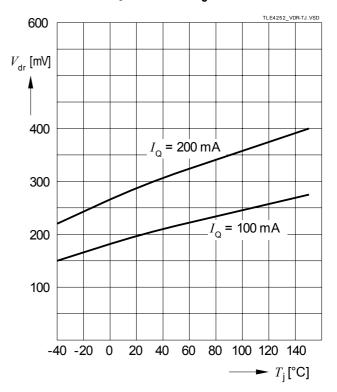
Current Consumption I_q versus Output Current I_Q



Drop Voltage $V_{\rm DR}$ versus Output Current $I_{\rm Q}$



Drop Voltage V_{DR} versus Junction Temperature T_{J}



Data Sheet



Package Outlines

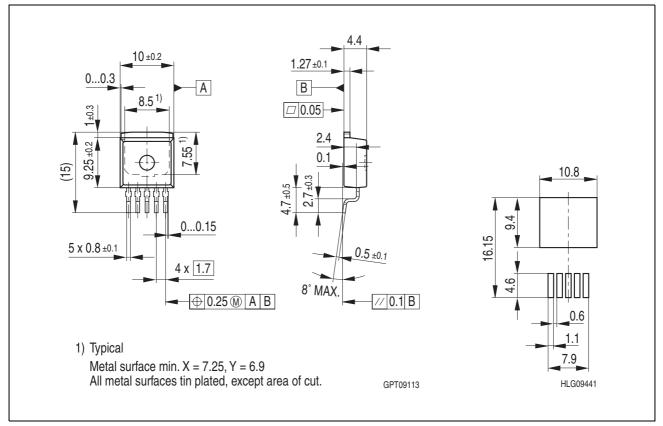


Figure 4 PG-TO263-5-1 Outline and Footprint (Reflow Soldering)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on Infineon packages, please visit our website: http://www.infineon.com/packages.

Dimensions in mm

Data Sheet



Revision History

Version	Date	Changes
Rev. 1.0	2008-05-09	Final datasheet TLE 4252 G. Corrected swaped numbers at Table 4 "Thermal Resistance PG-TO263-5" on Page 5 (value for 300mm ² vs. 600mm ²).
Rev. 0.9	2008-04-22	Initial Preliminary Datasheet of TLE 4252 G (PG-TO263-5).

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